PATENT Serial No: 09/504,623

Docket No. 2369/25

IN THE CLAIMS:

Please amend claims 4, 13 and 19 as follows:

- 1. (Previously Presented) A magnetoelectric device responsive to an applied magnetic field, comprising first and second ferromagnetic regions with a channel region between them, the ferromagnetic regions being configured so that charge carriers with a particular spin polarisation which can pass through the first region, pass through the second region as a function of the relative orientations of magnetisation of the ferromagnetic regions produced by the applied magnetic field whereby the device exhibits a conductivity as a function of the strength of the applied field, the channel region being configured to provide a quasi-one-dimensional channel to cause charge carriers which pass through the first ferromagnetic region to maintain their spin polarisation as they pass towards the second ferromagnetic region.
- 2. (Previously Presented) A magnetoelectric device according to claim 1 wherein the channel region includes a nanotube.
- 3. (Previously Presented) A magnetoelectric device according to claim 2 wherein the channel region comprises a bundle of nanotubes.
- 4. (Currently Amended) A magnetoelectric device according to claim 2 wherein the or each nanotube is made of carbon.
- 5. (Previously Presented) A magnetoelectric device according to claim 1 wherein the channel region comprises a layer of carbon containing material.
- 6. (Previously Presented) A magnetoelectric device according to claim 3 wherein the channel region comprises a layer of graphite.
- 7. (Previously Presented) A magnetoelectric device according to claim 3 wherein the channel region comprises a diamond layer.

8 - 12 canceled.

- 13. (Currently Amended) A magnetoelectric device responsive to an applied magnetic field, comprising first and second ferromagnetic regions with a channel region between them wherein the channel region includes a nanotube <u>providing a quasi-one-dimensional channel</u> between the first and second ferromagnetic regions.
- 14. (Previously Presented) A magnetoelectric device according to claim 13 wherein the channel region comprises a bundle of nanotubes.
- 15. (Previously Presented) A magnetoelectric device according to claim 13 wherein the nanotube is made of carbon.
- 16. (Previously Presented) A magnetoelectric device according to claim 13 wherein the nanotube is formed of boron nitride.
- 17. (Previously Presented) A magnetoelectric device according to claim 13 wherein the nanotube is formed of silicon.
- 18. (Previously Presented) A magnetoelectric device according to claim 1 wherein the first and second ferromagnetic regions comprise layers on a common substrate.
- 19. (Currently Amended) À magnetoelectric device according to claim 18 wherein the substrate <u>is</u> made of a material selected from a group consisting of a metal, glass and silicon, and <u>is</u> covered with an insulating layer on which the ferromagnetic layers are formed.
- 20. (Previously Presented) A magnetoelectric device according to claim 19 wherein the insulating layer comprises a material selected from a group consisting of silicon oxide and silicon nitride.

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21. (Previously Presented) A magnetoelectric device according to claim 1 wherein the first and second ferromagnetic regions are made of a cobalt containing material.

- 22. (Previously Presented) A magnetoeledctric device according to claim 1 including a gate to apply a field to the channel region.
- 23. (Previously Presented) A magnetic reading head for reading data from magnetic storage media, the head including a magnetoelectric device according to claim 1.
 - 24. Canceled.
- 25. (Previously Presented) A magnetic reading head for reading data from magnetic storage media, the head including a magnetoelectric device according to claim 13.